NSN 5962-01-378-7998



Memory Microcircuit - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5962-01-378-7998 **Maximum Power Dissipation Rating:** 300.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **Features Provided:** Bipolar and programmed and tested to mil-std-883 **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Bipolar metal-oxide semiconductor **Input Circuit Pattern:** 16 input **Case Outline Source And Designator:** D-8 mil-m-38510 **Terminal Surface Treatment:** Solder **Product Name:** Programmed array logic **Voltage Rating And Type Per Characteristic:** 4.5 volts applied and 5.5 volts applied **Memory Device Type:** Pal **Hybrid Technology Type:** Monolithic **Terminal Type And Quantity:** 20 printed circuit **Specification Data:** 81349-mil-m-38510 government specification and 67268-8506503ra government standard Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

Fiig:

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